

TOSHIBA Bipolar Linear Integrated Circuit Silicon Monolithic

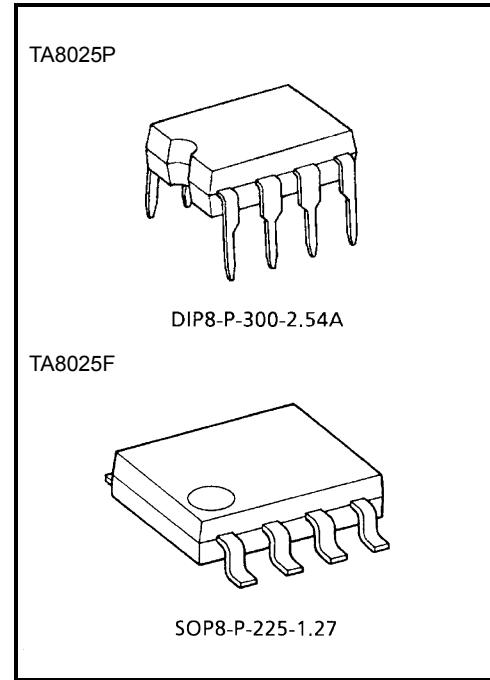
TA8025P,TA8025F

Pick Up Sensor Interface IC

The TA8025P TA8025F is an IC designed for making the output signal from electromagnetic pick up sensor and etc..., waveform-shaping. The Vth of input has hysteresis that is division value between peak voltage of input signal and 0V.

Features

- Input frequency : DC~50kHz
- Input voltage VTH : 0V \longleftrightarrow Vpeak×K
- Small package : DIP-8pin (TA8025P)
: SOP-8pin (TA8025F)
- Separate GND line for output and logic control sections

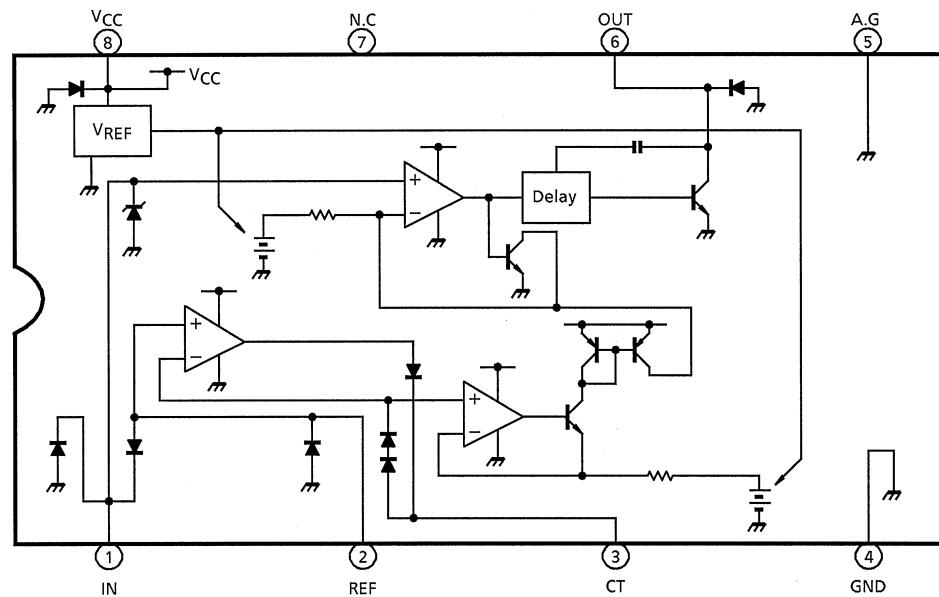


Weight

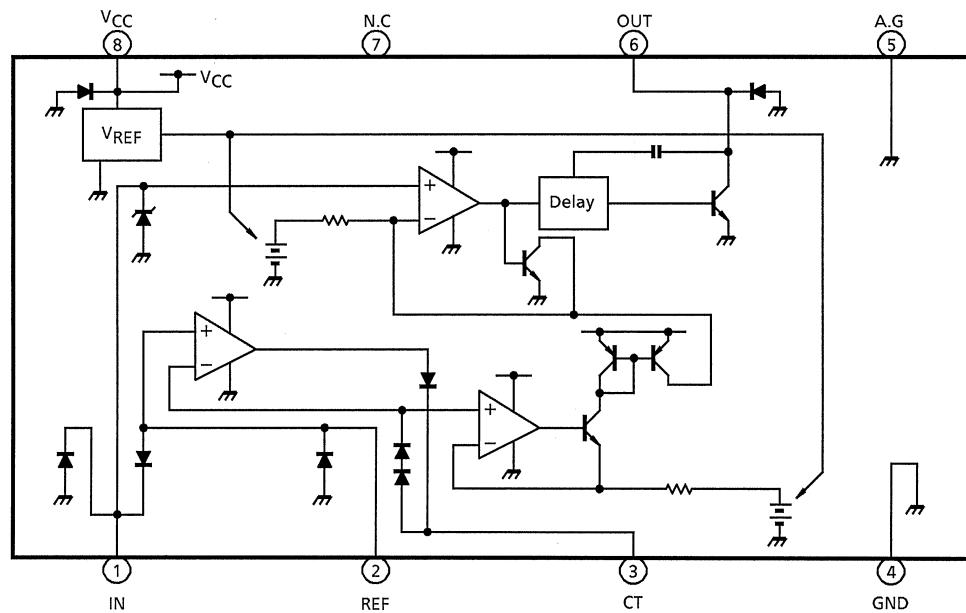
DIP8-P-300-2.54A : 0.45 g (typ.)
SOP8-P-225-1.27 : 0.08 g (typ.)

Block Diagram and Pin Layout

TA8025P



T8025F

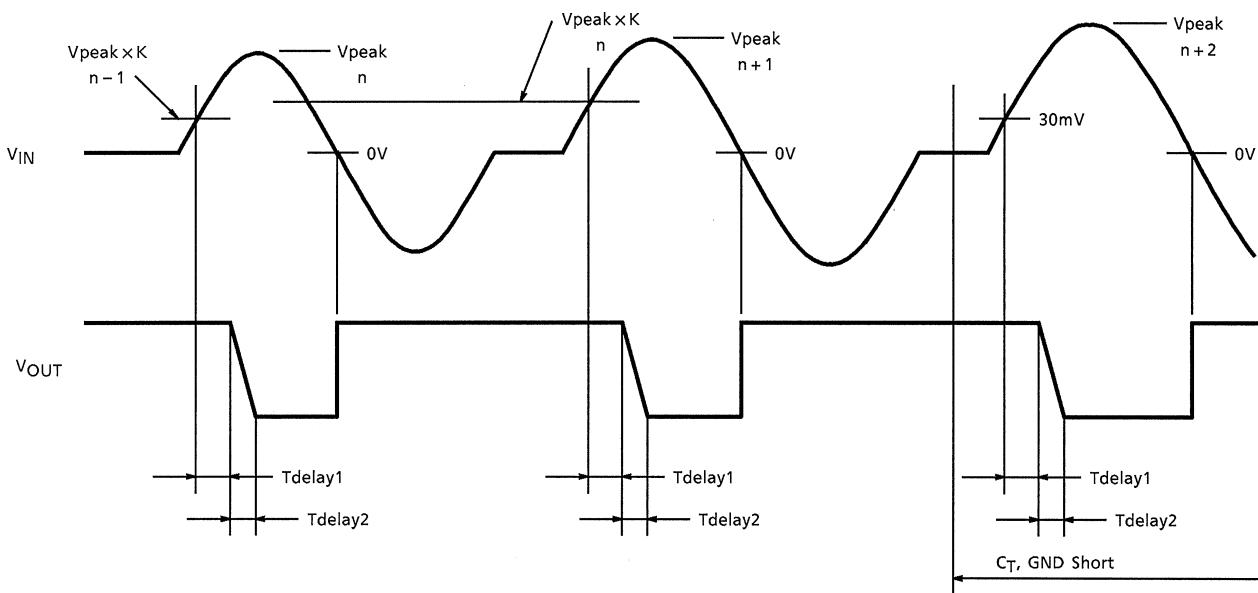


Note : The TA8025P and T8025F are the same chip; only the packages are different.

Pin Description

Pin No.	Symbol	Description
1	IN	Input pin for a signal from sensor.
2	REF	V_{TH} setting pin. The V_{TH} value can be set according to divide the input signal with resistors.
3	CT	This pin hold the peak value for input signal of REF pin.
4	GND	Grounded.
5	A.G	Grounded pin for REF.
6	OUT	The output is an NPN open-collector output and the input signal which is made waveform-shaping is gone out. When the output goes down, it has a slope of $1V/\mu s$ in order to lose the influence for the input signal.
7	N.C	Not connected. (Electrically, this pin is completely open.)
8	V _{CC}	Power supply pin.

Timing Chart



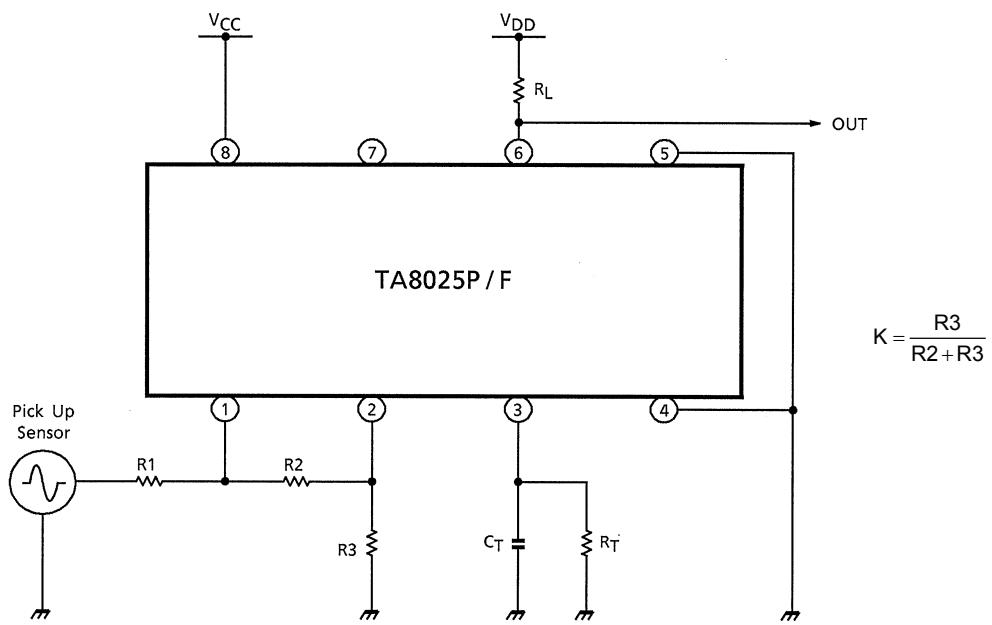
Note : See Electrical Characteristics for symbols in the timing chart.

Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Supply Voltage	V _{CC}	36	V
Input Voltage	V _{IN}	36	V
Input Current	I _{IN}	±20	mA
Output Current	I _{OUT}	10	mA
Power Dissipation	P _D	280	mW
Operating Voltage	V _{opr}	4.5~30	V
Operating Temperature	T _{opr}	-40~105	°C
Storage Temperature	T _{stg}	-55~150	°C
Lead Temperature-Time	T _{sol}	260 (10s)	°C

Electrical Characteristics (V_{CC} = 4.5~16V, Ta = -40~105°C)

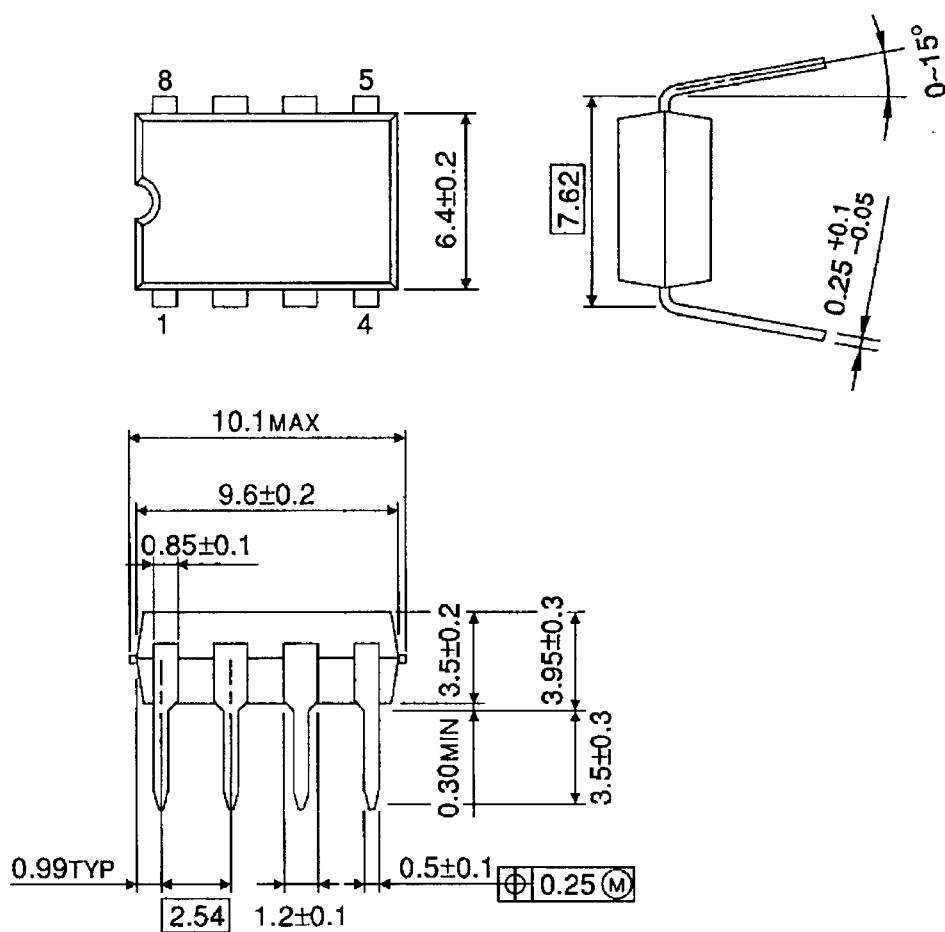
Characteristics	Symbol	Pin	Test CirCuit	Test Condition	Min	Typ.	Max	Unit	
Supply Current	I _{CC}	V _{CC}	—	Output : OFF	—	3.0	5.0	mA	
				Output : ON	—	4.5	8.0		
Input Current	I _{IN}	I _N	—	V _{IN} = 0V	-0.2	—	0.1	μA	
				V _{IN} = V _{CC}	-0.1	—	0.1		
High-Side Minimum Threshold Voltage	V _{TH1}		—	V _{REF} = 0V	24	30	36	mA	
					-20	—	20		
Zener Voltage	V _Z		—	I _{IN} = 1mA	24	30	36	V	
Input Current	I _{IN}	REF	—	V _{IN} = 0V	-0.2	—	0.1	μA	
				V _{IN} = V _{CC}	-0.1	—	0.1		
Output Voltage	V _{OL}	OUT	—	I _{OL} = 5mA	—	—	0.5	V	
Output Leakage Current	I _{LEAK}		—	V _{OH} = 5V	-5.0	—	5.0	μA	
Output Delay Time	T _{delay1}	OUT	—	V _{CC} = 16V	—	7.5	20.0	μs	
	T _{delay2}		—	V _{DD} = 5V	—	5.0	10.0		

Example of Application Circuit

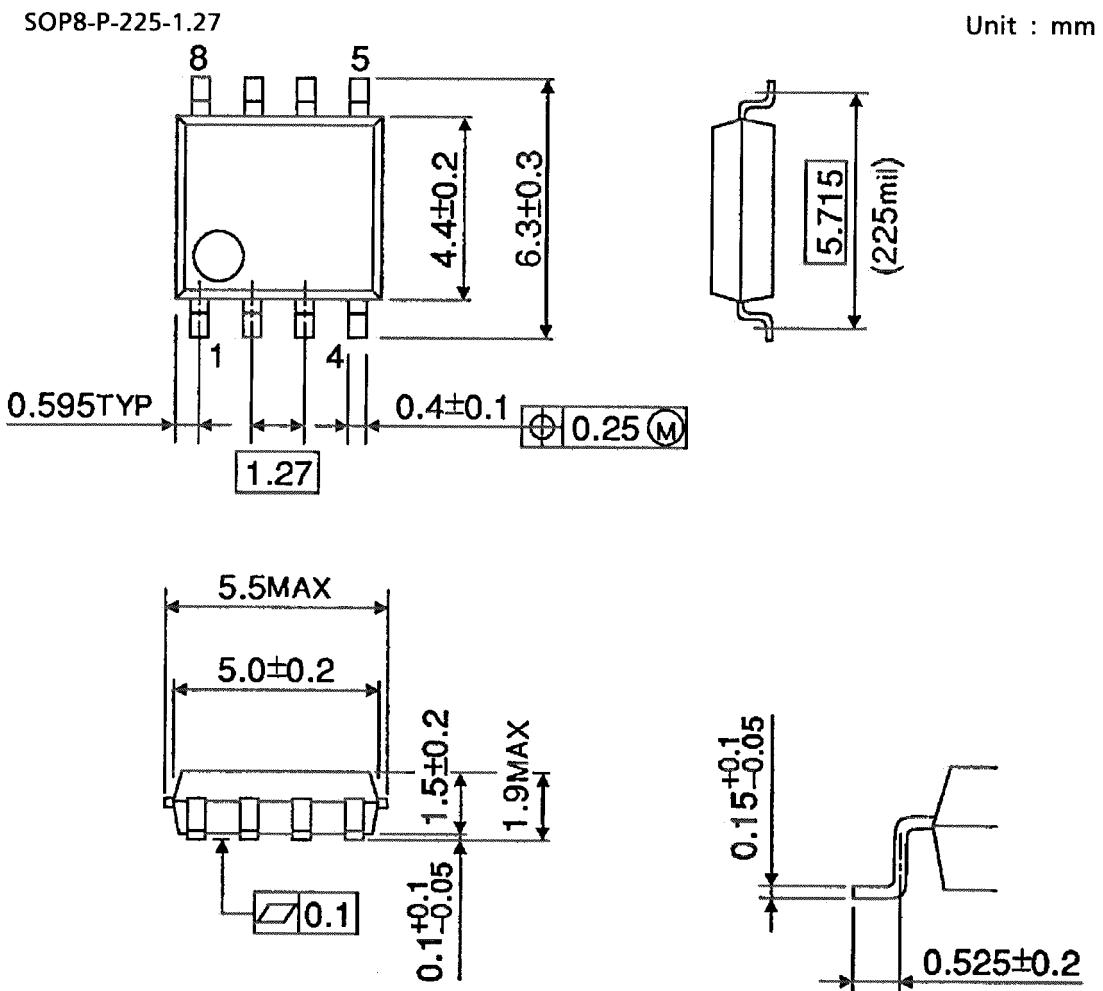
Package Dimensions

DIP8-P-300-2.54A

Unit : mm



Weight: 0.45 g (typ.)

Package Dimensions

Weight: 0.08 g (typ.)

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